

2SC5049

Silicon NPN Epitaxial

REJ03G0740-0300 (Previous ADE-208-1129A) Rev.3.00 Aug.10.2005

Application

VHF / UHF wide band amplifier

Features

• High gain bandwidth product $f_T = 10 \text{ GHz Typ}$

High gain, low noise figure
 PG = 15.0 dB Typ, NF = 1.2 dB Typ at f = 900 MHz

Outline

RENESAS Package code: PLSP0003ZB-A (Package name: MPAK)

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1. Emitter

2. Base

3. Collector

Note: Marking is "YA-".

Attention: This device is very sensitive to electro static discharge.

It is recommended to adopt appropriate cautions when handling this transistor.

Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Collector to base voltage	V_{CBO}	15	V
Collector to emitter voltage	V_{CEO}	8	V
Emitter to base voltage	V_{EBO}	1.5	V
Collector current	I _C	20	mA
Collector power dissipation	Pc	150	mW
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

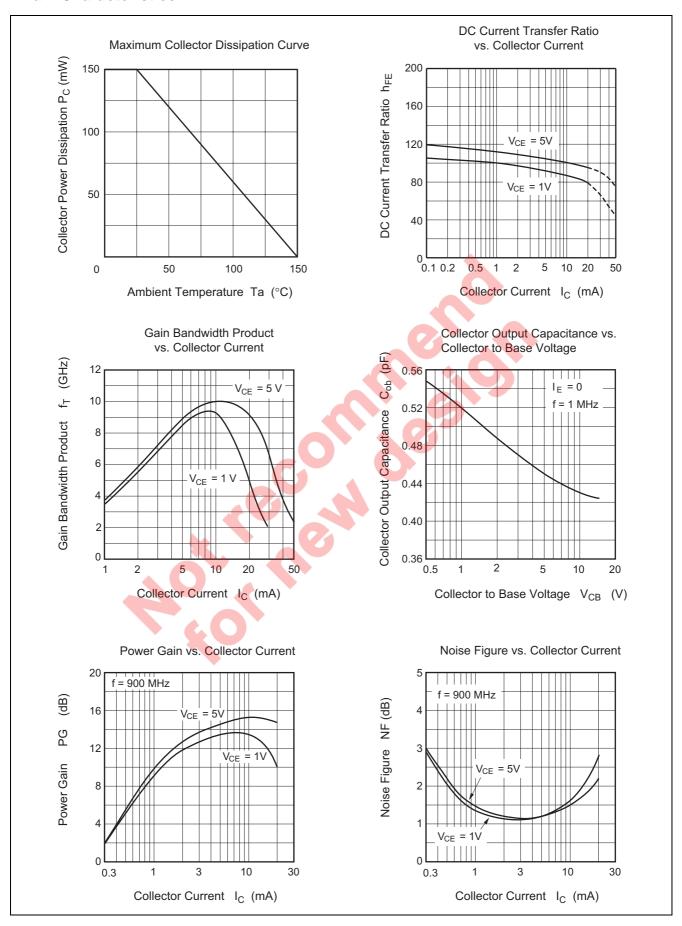
Electrical Characteristics

 $(Ta = 25^{\circ}C)$

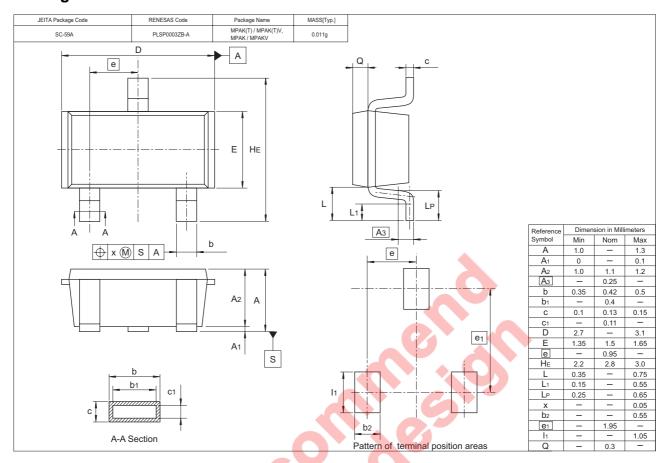
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Collector cutoff current	I _{CBO}	_	_	10	μΑ	V _{CB} = 15 V, I _E = 0
	I _{CEO}	_	_	1	mA	$V_{CE} = 8 \text{ V}, R_{BE} = \infty$
Emitter cutoff current	I _{EBO}	_	_	10	μΑ	$V_{EB} = 1.5 \text{ V}, I_C = 0$
DC current transfer ratio	h _{FE}	50	120	250		$V_{CE} = 5 \text{ V}, I_{C} = 20 \text{ mA}$
Collector output capacitance	Cob	_	0.45	0.8	pF	$V_{CB} = 5 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$
Gain bandwidth product	f⊤	7.0	10.0	_	GHz	$V_{CE} = 5 \text{ V}, I_{C} = 10 \text{ mA}$
Power gain	PG	12.0	15.0	_	dB	$V_{CE} = 5 \text{ V}, I_{C} = 10 \text{ mA},$ f = 900 MHz
Noise figure	NF	_	1.2	2.5	dB	$V_{CE} = 5 \text{ V}, I_{C} = 5 \text{ mA},$ f = 900 MHz



Main Characteristics



Package Dimensions



Ordering Information

Part Name	Quantity		Shipping Container
2SC5049YA-TL-E	3000	φ ′	78 mm Reel, 8 mm Emboss Taping

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.

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